



PJQ4431EP-AU

30V P-Channel Enhancement Mode MOSFET

Voltage **-30 V** **Current** **-78 A**

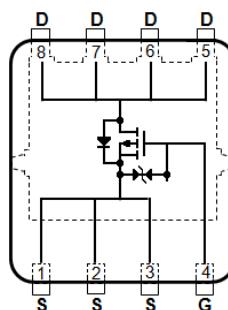
Features

- $R_{DS(ON)}$, $V_{GS} @ -10V$, $I_D @ -10A < 7m\Omega$
- $R_{DS(ON)}$, $V_{GS} @ -4.5V$, $I_D @ -6A < 11.1m\Omega$
- 100% UIS tested
- Reliable and Rugged
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : DFN3333-8L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.03 grams

DFN3333-8L



Maximum Ratings and Thermal Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNITS
Drain-Source Voltage	V_{DS}	-30	V
Gate-Source Voltage	V_{GS}	± 25	
Continuous Drain Current ^(Note 3)	I_D	-78	A
$T_C=100^\circ\text{C}$		-52	
Pulsed Drain Current ^(Note 1)	I_{DM}	-209	A
Power Dissipation	P_D	68	
$T_C=100^\circ\text{C}$		34	
Continuous Drain Current ^(Note 4)	I_D	-15	A
$T_A=70^\circ\text{C}$		-12.5	
Power Dissipation	P_D	2.5	W
$T_A=70^\circ\text{C}$		1.8	
Single Pulse Avalanche Energy ^(Note 5)	E_{AS}	121	mJ
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55~175	°C
Thermal Resistance ^(Note 4)	Junction to Case	$R_{\theta JC}$	°C/W
	Junction to Ambient	$R_{\theta JA}$	



PJQ4431EP-AU

Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =-250uA	-30	-	-	V
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250uA	-1	-1.8	-2.5	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-10V, I _D =-10A	-	5.6	7	mΩ
		V _{GS} =-4.5V, I _D =-6A	-	8.5	11.1	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-30V, V _{GS} =0V	-	-	-1	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±25V, V _{DS} =0V	-	-	±10	uA
		V _{GS} =±10V, V _{DS} =0V	-	-	±1	
Dynamic ^(Note 6)						
Total Gate Charge	Q _g	V _{DS} =-24V, I _D =-10A, V _{GS} =-10V	-	68	-	nC
Gate-Source Charge	Q _{gs}		-	9	-	
Gate-Drain Charge	Q _{gd}		-	20	-	
Input Capacitance	C _{iss}	V _{DS} =-25V, V _{GS} =0V, f=1MHz	-	3040	-	pF
Output Capacitance	C _{oss}		-	435	-	
Reverse Transfer Capacitance	C _{rss}		-	340	-	
Gate resistance	R _g	f=1MHz	-	2.2	-	Ω
Turn-On Delay Time	t _{d(on)}	V _{DS} =-24V, I _D =-10A, V _{GS} =-10V, R _G =3Ω (Note 2)	-	12	-	ns
Turn-On Rise Time	t _r		-	15	-	
Turn-Off Delay Time	t _{d(off)}		-	50	-	
Turn-Off Fall Time	t _f		-	31	-	
Drain-Source Diode						
Diode Forward Current	I _s	T _C =25°C	-	-	-78	A
Pulsed Diode Forward Voltage	I _{SM}		-	-	-209	
Diode Forward Voltage	V _{SD}	I _s =-20A, V _{GS} =0V	-	-0.85	-1.3	V
Reverse Recovery Time	T _{rr}	V _{GS} =0V, I _s =-20A dI _s /dt=100A/us	-	26	-	ns
Reverse Recovery Charge	Q _{rr}		-	16	-	nC

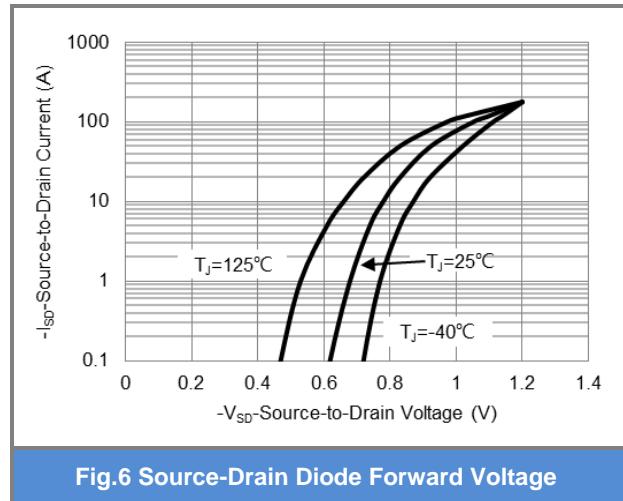
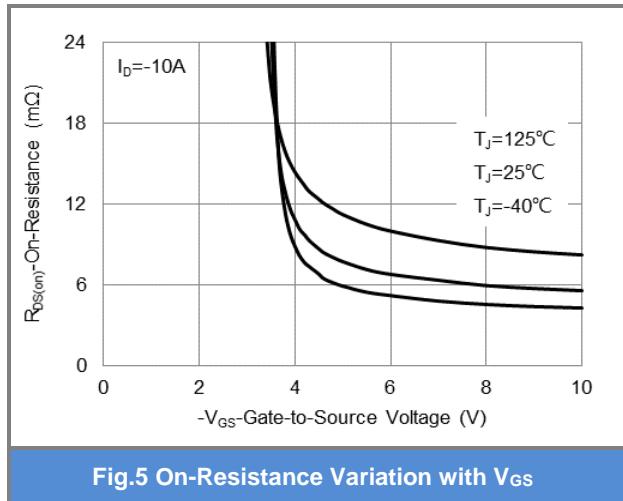
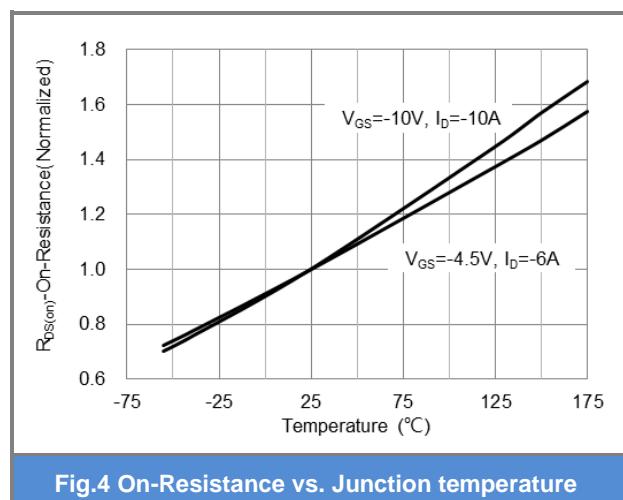
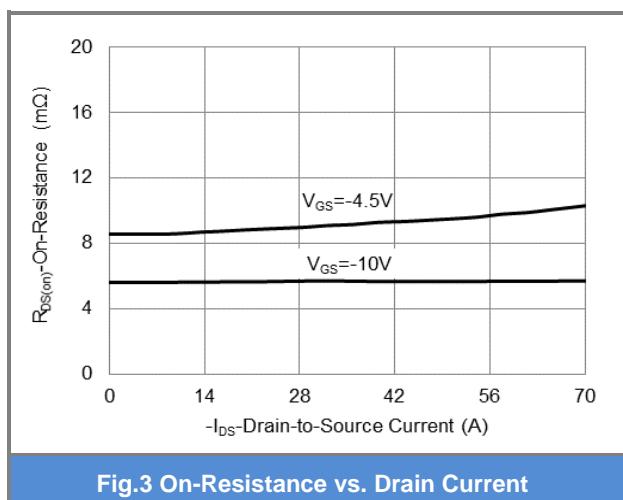
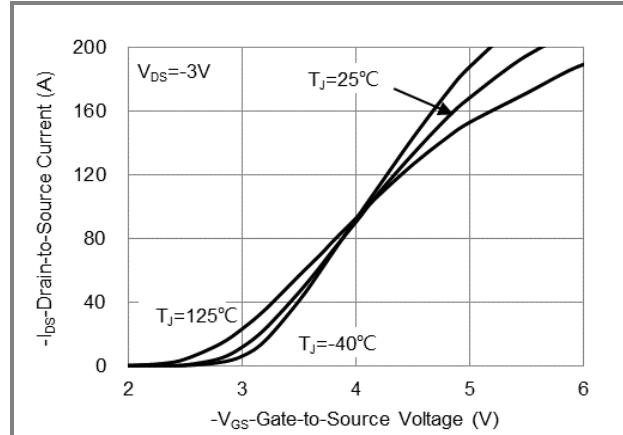
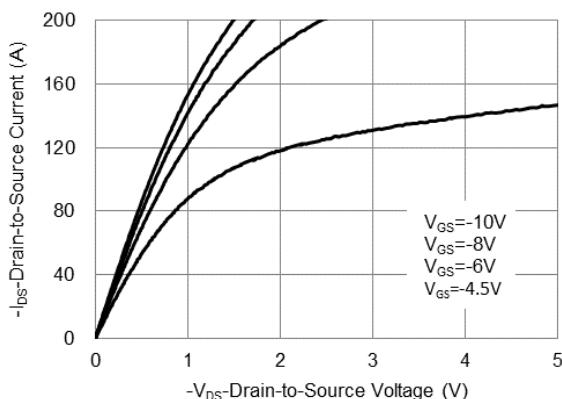
NOTES :

1. Pulse width≤300us, Duty cycle≤2%.
2. Essentially independent of operating temperature typical characteristics.
3. The maximum current rating is package limited.
4. R_{θJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
5. The test condition is L=0.5mH, I_{AS}=-22A, V_{DD}=-30V, V_{GS}=-10V, Starting T_J=25°C.
6. Guaranteed by design, not subject to production testing.



PJQ4431EP-AU

TYPICAL CHARACTERISTIC CURVES





PJQ4431EP-AU

TYPICAL CHARACTERISTIC CURVES

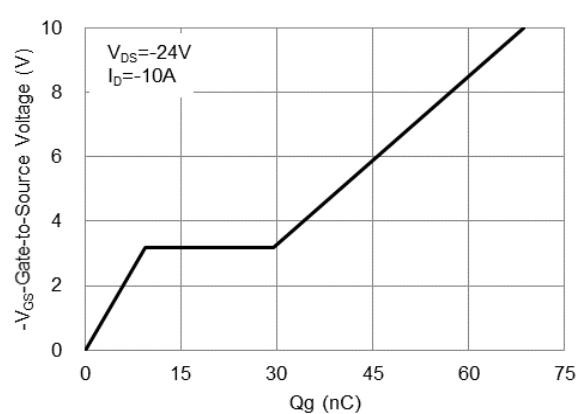


Fig.7 Gate-Charge Characteristics

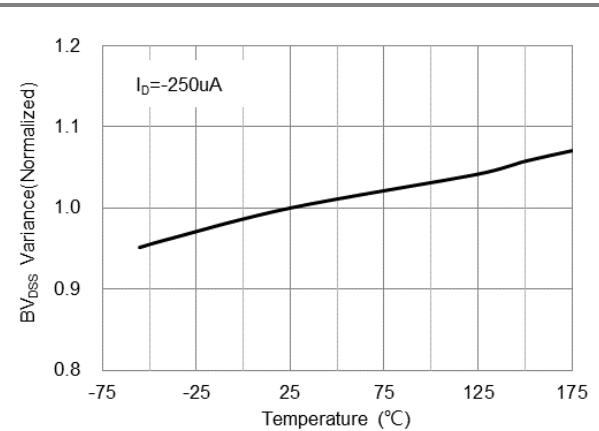


Fig.8 Breakdown Voltage Variation vs. Temperature

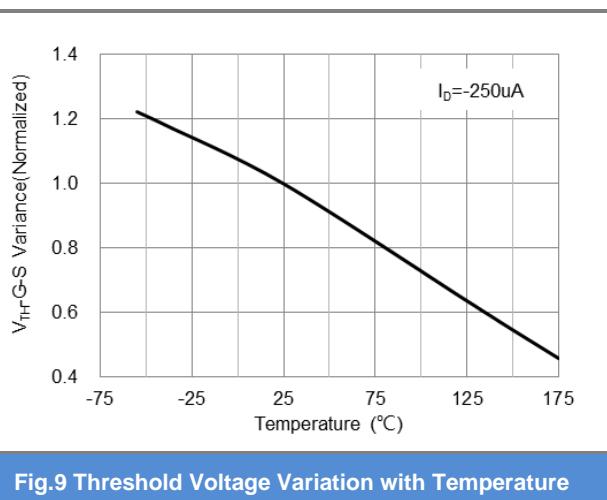


Fig.9 Threshold Voltage Variation with Temperature

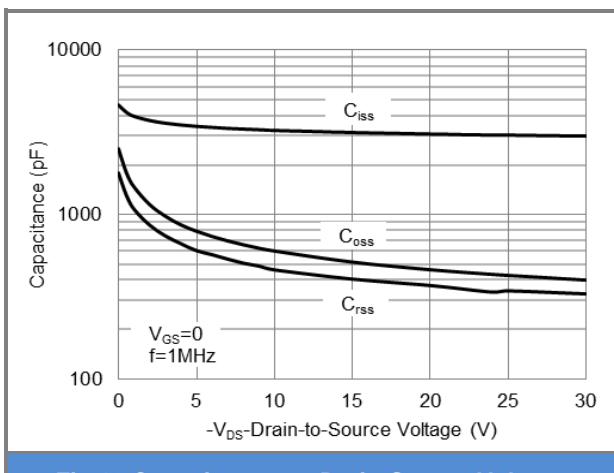


Fig.10 Capacitance vs. Drain-Source Voltage

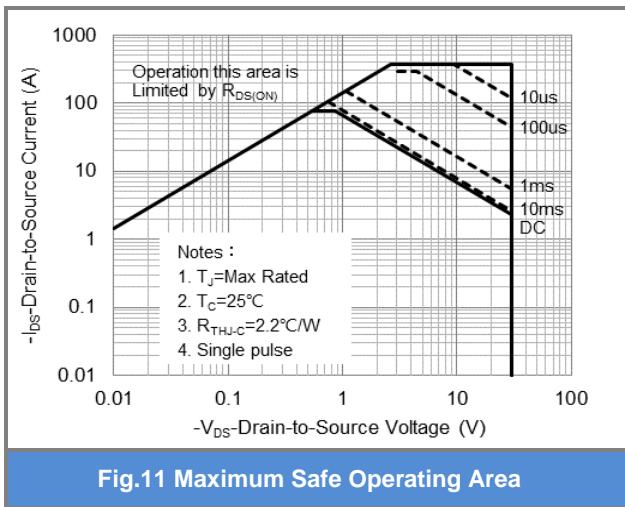


Fig.11 Maximum Safe Operating Area

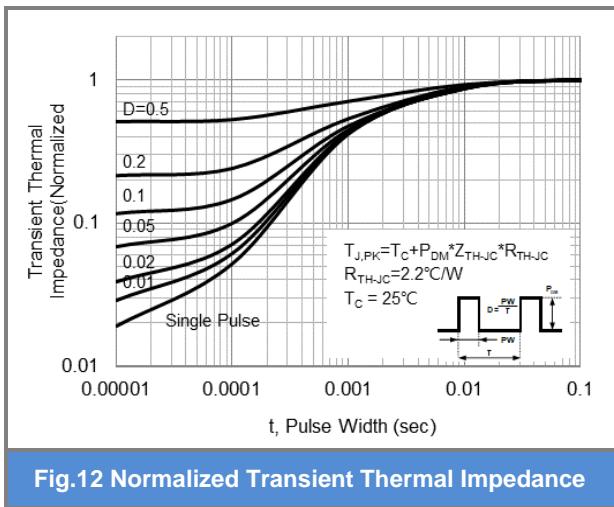


Fig.12 Normalized Transient Thermal Impedance

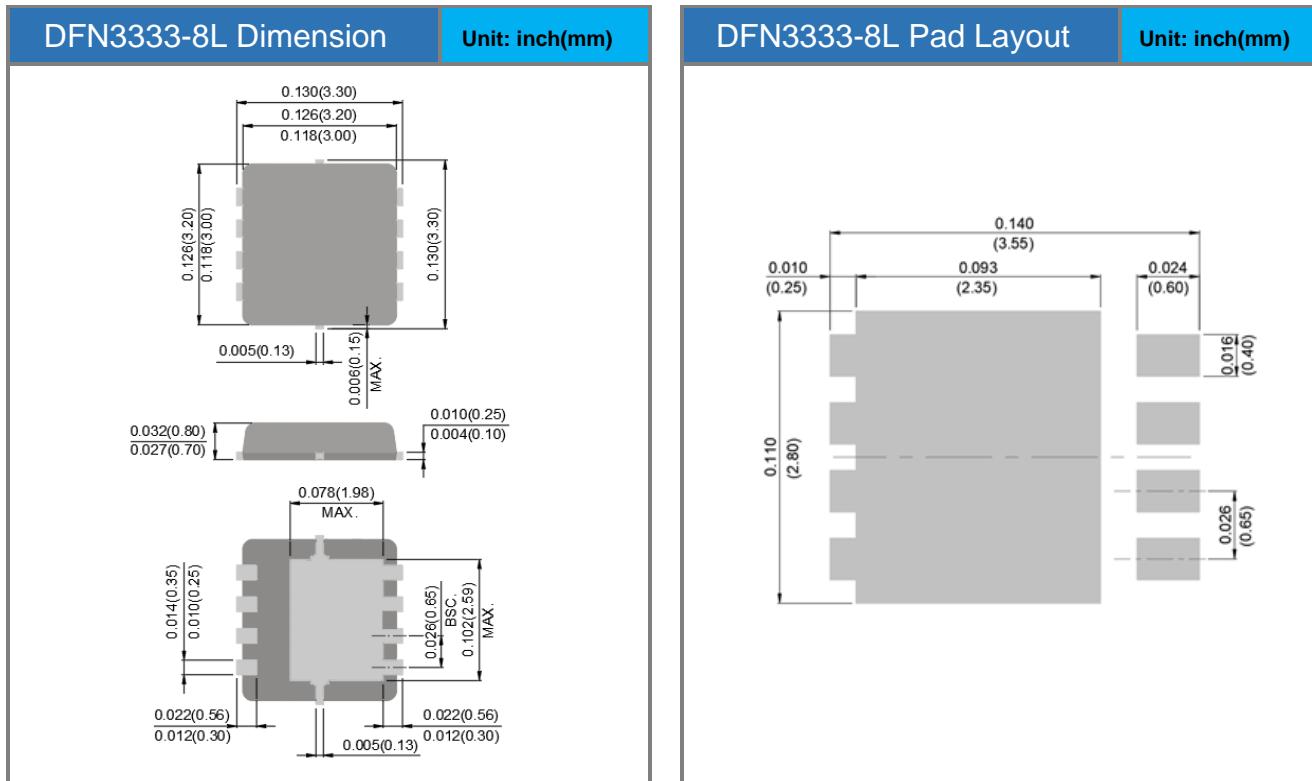


PJQ4431EP-AU

Product and Packing Information

Part No.	Package Type	Packing Type	Marking
PJQ4431EP-AU	DFN3333-8L	5K pcs / 13" reel	431E

Packaging Information & Mounting Pad Layout





PJQ4431EP-AU

Disclaimer

- Reproducing and modifying information of the document is prohibited without permission from Panjit International Inc..
- Panjit International Inc. reserves the rights to make changes of the content herein the document anytime without notification. Please refer to our website for the latest document.
- Panjit International Inc. disclaims any and all liability arising out of the application or use of any product including damages incidentally and consequentially occurred.
- Panjit International Inc. does not assume any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.
- Applications shown on the herein document are examples of standard use and operation. Customers are responsible in comprehending the suitable use in particular applications. Panjit International Inc. makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.
- The products shown herein are not designed and authorized for equipments relating to human life and for any applications concerning life-saving or life-sustaining, such as medical instruments, aerospace machinery et cetera. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Panjit International Inc. for any damages resulting from such improper use or sale.
- Since Panjit uses lot number as the tracking base, please provide the lot number for tracking when complaining.